L Number	Hits	Search Text	DB	Time stamp
1	16	"5902690"	USPAT;	2004/02/09 10:02
			US-PGPUB	
2	0	10/074394	USPAT;	2004/02/09 09:47
l			US-PGPUB	
3	2546	("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT,	2004/02/09 10:06
		(ferromagnetic insulat\$3)	US-PGPUB	
4	2546	(("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:07
		(ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	
		near4 memory ferromagnetic insulat\$3)		
5	50	((("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:14
		(ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	
		near4 memory ferromagnetic insulat\$3)) and ((permeable permeability		
		permeab\$4) with (shiled\$1 shielding))		
6	50	(((("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:12
		(ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	
		near4 memory ferromagnetic insulat\$3)) and ((permeable permeability		
		permeab\$4) with (shiled\$1 shielding))) and (permeable permeability		
		permeab\$4 shiled\$1 shielding)		
7	50	((("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:13
		(ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	
		near4 memory ferromagnetic insulat\$3)) and ((permeable permeability		
		permeab\$4) with (shieldd\$1 shielding))		
8	. 50	(((("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:13
		(ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	
		near4 memory ferromagnetic insulat\$3)) and ((permeable permeability		
		permeab\$4) with (shieldd\$1 shielding))) and (permeable permeability		
	1.40	permeab\$4 shieldd\$1 shielding)	LIODAT	2004/02/00 10:14
9	148	((("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:14
		(ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	
		near4 memory ferromagnetic insulat\$3)) and ((permeable permeability		
10	148	permeab\$4) with (shield\$1 shielding)) (((("MRAM" magnetoresistive magnetic\$4 near4 memory) with	USPAT;	2004/02/09 10:14
10	146	((((MRAW magnetoresistive magnetics4 means) with (ferromagnetic insulat\$3)) and ("MRAM" magnetoresistive magnetic\$4	US-PGPUB	2004/02/09 10.14
		near4 memory ferromagnetic insulat\$3)) and ((permeable permeability	OB-1 OI OD	
		permeab\$4) with (shield\$1 shielding))) and (permeable permeability		
		permeab\$4 shield\$1 shielding)		
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12	1		USPAT	2004/02/09 13:33
13	1		USPAT	2004/02/09 13:33
14	1		USPAT	2004/02/09 13:37
15	1		USPAT	2004/02/09 13:39
16	1		USPAT	2004/02/09 13:39
17	1		USPAT	2004/02/09 13:39
18	1		USPAT	2004/02/09 13:40
19	1		USPAT	2004/02/09 13:43
20	1		USPAT	2004/02/09 13:45
21	1		USPAT	2004/02/09 13:45
22	1		USPAT	2004/02/09 13:47
23	1		USPAT	2004/02/09 13:56
24	1		USPAT	2004/02/09 13:56
25	1		USPAT	2004/02/09 13:56
26	1		USPAT	2004/02/09 13:56
27	1	·	USPAT	2004/02/09 13:56
28	1		USPAT	2004/02/09 13:56
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30	I		USPAT	2004/02/09 14:31